## **Vishay Semiconductors**

## **Thyristor/Thyristor** (SUPER MAGN-A-PAK Power Modules), 570 A



- · High current capability
- · High surge capability
- · Industrial standard package
- $\bullet$  3000  $V_{\text{RMS}}$  isolating voltage with non-toxic substrate
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for industrial level

#### **TYPICAL APPLICATIONS**

- Motor starters
- · DC motor controls AC motor controls
- · Uninterruptable power supplies

- 40 to 135

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>T(AV)</sub>	T <sub>C</sub> = 74 °C	570					
I <sub>T(RMS)</sub>	T <sub>C</sub> = 74 °C	895	٨				
ITSM	50 Hz	17 800	A				
	60 Hz	18 700					
l <sup>2</sup> t	50 Hz	1591	kA <sup>2</sup> s				
1-1	60 Hz	1452	KA-S				
l²√t		15 910	kA²√s				
V <sub>RRM</sub>		1800	V				
T <sub>Stg</sub>	Range	- 40 to 135	°C				
_	_						

#### **ELECTRICAL SPECIFICATIONS**

 $\mathsf{T}_\mathsf{J}$ 

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA			
VSKT570-18PbF	18	1800	1900	120			



SUPER MAGN-A-PAK

PRODUCT SUMMARY				
I <sub>T(AV)</sub>	570 A			

Range

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ON-STATE CONDUCTION						
PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current	L	180° conduction	n, half sine wave		570	А
at case temperature	I <sub>T(AV)</sub>		i, nali sine wave		74	°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	180° conduction	n, half sine wave	at T <sub>C</sub> = 74 °C	895	А
		t = 10 ms	No voltage		17.8	- kA
Maximum peak, one-cycle,	I <sub>TSM,</sub>	t = 8.3 ms	reapplied		18.7	
non-repetitive on-state surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal	15.0	
		t = 8.3 ms	reapplied		15.7	
		t = 10 ms	No voltage	half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	1591	kA <sup>2</sup> s
Manutine 124 6 6 in a	l <sup>2</sup> t	t = 8.3 ms	reapplied		1452	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		1125	
		t = 8.3 ms	reapplied		1027	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		15 910	kA²√s	
Low level value or threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.864	v	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J maximum$		0.97	v	
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.411	mΩ	
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J maximum$		0.362	1115.2	
Maximum on-state voltage drop	V <sub>TM</sub>	$I_{pk}$ = 1500 A, $T_J$ = 25 °C, $t_p$ = 10 ms sine pulse		1.50	V	
Maximum holding current	Ι <sub>Η</sub>	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		500	mA	
Maximum latching current	١L			1000		

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum rate of rise of turned-on current	dl/dt	$T_J = T_J$ maximum, $I_{TM} = 400$ A, $V_{DRM}$ applied	1000	A/µs	
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	2.0		
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 750 A; T <sub>J</sub> = T <sub>J</sub> maximum, dl/dt = - 60 A/µs, V <sub>R</sub> = 50 V, dV/dt = 20 V/µs, gate 0 V 100 Ω	200	μs	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of off-state voltage	dV/dt	$T_{J}$ = $T_{J}$ maximum, linear to $V_{D}$ = 80 $\%~V_{DRM}$	1000	V/µs	
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V	
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	120	mA	

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## Thyristor/Thyristor (SUPER MAGN-A-PAK Power Modules), 570 A

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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $t_p \le 5$ ms	10	w	
Maximum peak average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, f = 50 Hz, d% = 50	2.0	vv	
Maximum peak positive gate current	+I <sub>GM</sub>		3.0	A	
Maximum peak positive gate voltage	+V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	20	V	
Maximum peak negative gate voltage	-V <sub>GM</sub>		5.0	v	
Maximum DC gate current required to trigger	I <sub>GT</sub>	T - 25 °C V 12 V	200	mA	
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C, V <sub>ak</sub> 12 V	3.0	V	
DC gate current not to trigger	I <sub>GD</sub>	$T_J = T_J maximum$	10	mA	
DC gate voltage not to trigger	$V_{GD}$		0.25	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	TJ		- 40 to 135	°C
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 135	
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.065	K/W
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>		0.02	10.00
SMAP to heatsin Mounting torque ± 10 %	ĸ	A mounting compound is recommended and the torque should be rechecked after a period of	6-8	Nm
busbar to SMAI	þ	3 hours to allow for the spread of the compound.	12-15	NIII
Approximate weight			1500	g
Case style		See dimensions (link at the end of datasheet)	SUPER MA	GN-A-PAK

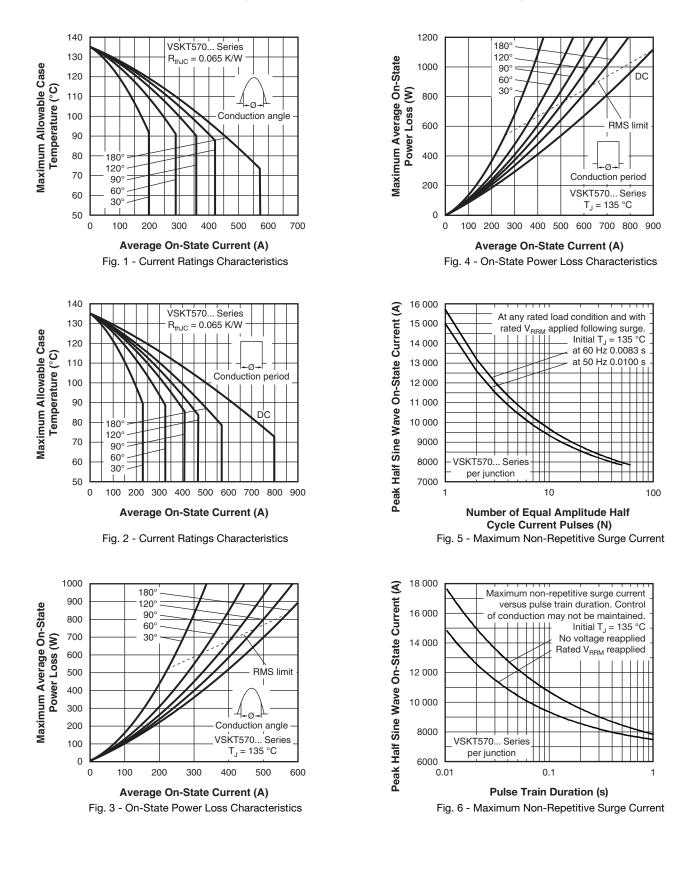
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.009	0.006			
120°	0.011	0.011			
90°	0.014	0.015	$T_J = T_J maximum$	K/W	
60°	0.021	0.022			
30°	0.037	0.038			

Note

Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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Thyristor/Thyristor (SUPER MAGN-A-PAK Power Modules), 570 A

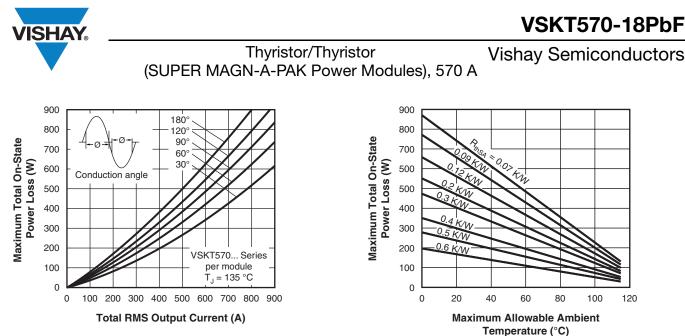


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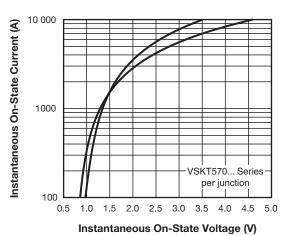


Fig. 8 - On-State Voltage Drop Characteristics

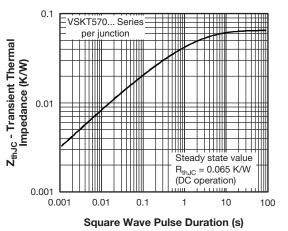
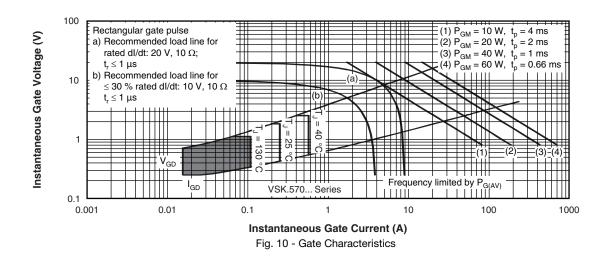


Fig. 9 - Thermal Impedance ZthJC Characteristics



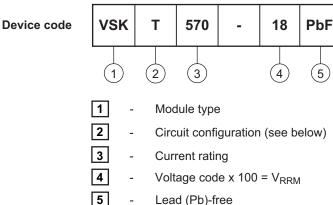
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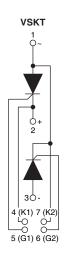


## **ORDERING INFORMATION TABLE**



Lead (Pb)-free

### **CIRCUIT CONFIGURATION**



LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95283

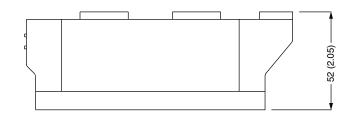
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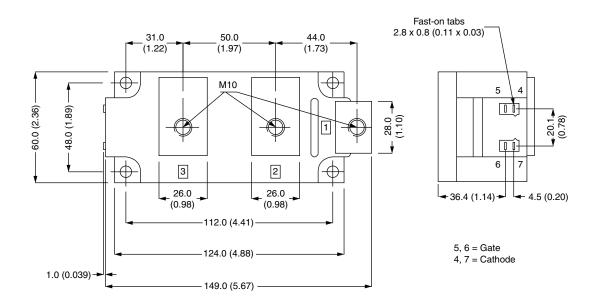


Vishay Semiconductors

# Super MAGN-A-PAK Thyristor/Diode

#### **DIMENSIONS** in millimeters (inches)







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